

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low $V_{\mbox{\scriptsize F}}$
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

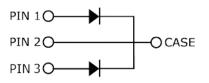
Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Qty(PCS)	
HIDW40G65C5BXKSA2	TO-247	30	







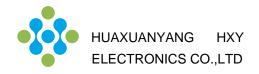


Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	Vrrm	650	V
Surge Peak Reverse Voltage	Vrsm	650	V
DC Peak Reverse Voltage	Vr	650	V
Continuous Forward Current $Tc = 25^{\circ}C$ $Tc = 135^{\circ}C$ $Tc = 160^{\circ}C$	lF	51/102 26/52 20/40	A
Repetitive Peak Forward Surge Current $Tc = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $Tc = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	IFRM	102 63	A
Non-Repetitive Forward Surge Current $Tc = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $Tc = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	IFSM	150 120	A
i²dt value Tc = 25°C,t _P =10ms,Half Sine Pulse Tc = 110°C,t _P =10ms,Half Sine Pulse	∫ i²dt	112 72	A²s
Power dissipation Tc = 25°C Tc = 110°C	Ptot	150/300 62/130	W
Operating junction Range	Tj	-55 to +175	°C
Storage temperature Range	Tstg	-55 to +150	°C

Thermal Resistance

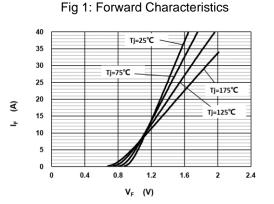
Parameter	Symbol	Value	Unit
Thermal resistance, junction – case.	RthJC	1.0/0.5	°C/W

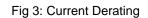


Baramatar	Symbol	Value		Unit	Test Condition		
Parameter	Symbol	min.	typ.	max.	Unit	Test Condition	
Forward Voltage	VF					I⊧=20A	
		-	1.35	1.5	V	Tj=25°C	
		-	1.65	1.8		Tj=175°C	
Reverse Current	lr				μΑ	Vr=650V	
		-	2	40		Tj=25°C	
		-	10	100		Tj=175°C	
Total Capacitive Charge	Qc	-	52	-	nC	V ≈=400V,Tj=25° ℃	
						$Q_{C} = \int_{0}^{V_{R}} C(V) dV$	
Total Capacitance	С				pF	Tj =25 ℃, f=1MHz	
		-	1018	-		Vr=0V	
		-	104	-		VR=200V	
		-	89	-		VR=400V	

Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

Characteristics Curve:





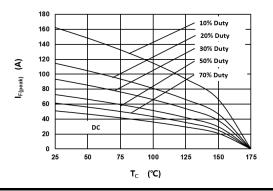
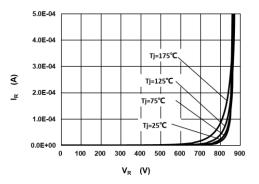
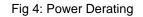
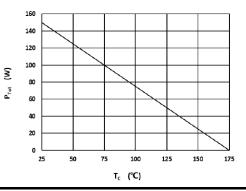


Fig 2: Reverse Characteristics







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Fig 5: Capacitance vs. Reverse Voltage

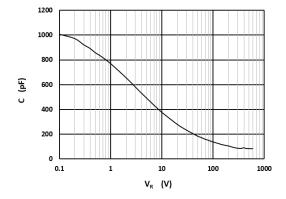


Fig 7: Typical Capacitance Stored Energy

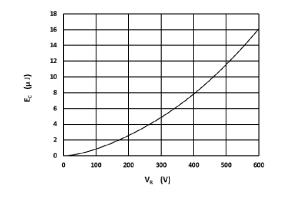


Fig 6: Reverse Charge vs. Reverse Voltage

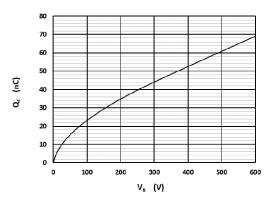
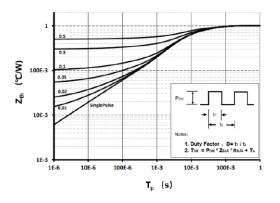


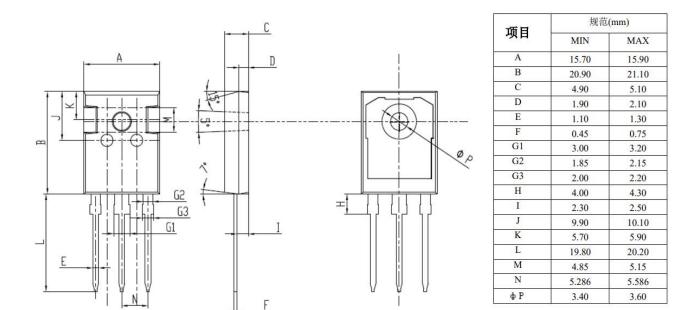
Fig 8: Transient Thermal Impandance

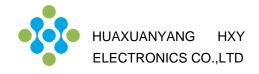




Package Dimensions

Package TO-247





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